

3A Step-Down Adjustable Voltage Regulator in bare die form

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Description

The SiS2576-ADJ is a monolithic step-down(buck) switching regulator provisioned to drive 3A loads with very tight line and load regulation. The device is internally equipped with frequency compensation and fixed frequency oscillator. The device delivers higher efficiency than the traditional 3-terminal linear regulator and enables reduction or in some cases elimination of heat sinking. The SiS2576 operates with a minimal number of external components and makes use of a widely available and optimized inductor to simplify switchmode power design. The device features a guaranteed ±4% output voltage (within specified input voltages and output load conditions) and ±10% oscillator frequency tolerance. External shutdown is integrated and features 50µA (typical) standby current. The output switch is equipped with cycle-by-cycle current limiting and thermal shutdown for full protection during fault conditions.

Features:

- Adjustable output range
- Guaranteed output current
- Wide 40V input range
- Requires x6 external components only
- 52kHz fixed frequency internal oscillator
- TTL shutdown capability, low power standby mode
- High efficiency
- Uses readily available standard inductors
- Thermal shutdown and current limit protection
- Reduced heat sink requirement versus linear regulators.

Ordering Information

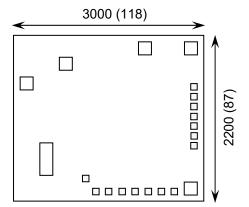
The following part suffixes apply:

No suffix - MIL-STD-883 /2010B Visual Inspection

For High Reliability versions of this product please see

SiS1576-ADJ

Die Dimensions in µm (mils)



Supply Formats:

- Default Die in Waffle Pack (100 per tray capacity)
- Sawn Wafer on Tape On request
- Unsawn Wafer On request
- Die Thickness <> 380µm(15 Mils) On request
- Assembled into in TO-220 package On request

Mechanical Specification

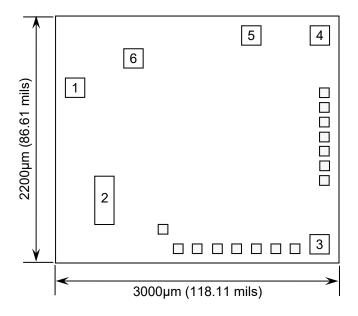
| Die Size (Un-sawn) | 3000 x 2200 118 x 87 | µm mils | |
|------------------------|----------------------------|------------|--|
| Minimum Bond Pad Size | 150 x 150 5.90 x 5.90 | μm mils | |
| Die Thickness | 380 (±20) 14.96 (±0.79) | μm mils | |
| Top Metal Composition | Al | | |
| Back Metal Composition | N/A – Bare Si | | |





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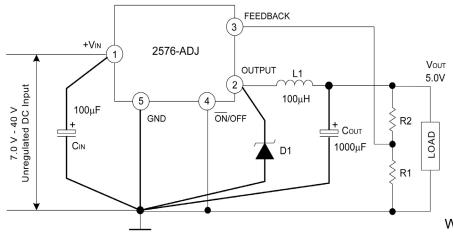
Pad Layout and Functions



COORDINATES PAD FUNCTION (µm) Υ X 1 V_{IN} 83 1439 2 V_{OUT} 827 403 3 **FEEDBACK** 2767 83 ON / OFF 4 2767 1967 5 **GND** 2277 1967 6 V_{IN} 1071 1694 **GROUND CHIP BACKSIDE**

Pinout (Assembled in TO-220)

Functional Diagram (Pad assignment)



| 5 4 - FEEDBACK 1 3 4 5 - ON/OFF |
|------------------------------------|
|------------------------------------|

 C_{IN} - 100 μ F, 75V, Aluminum Electrolytic C_{OUT} - 1000 μ F, 25V, Aluminum Electrolytic

D1 - Schottky, MBR360

L1 - 100µH, Pulse Eng. PE-92108

R1 - 2kΩ, 0.1%

R2 - $6.12k\Omega,\,0.1\%$

$$V_{OUT} = V_{REF} (1 + \frac{R2}{R1})$$

$$R2 = R1 (\frac{V_{OUT}}{V_{REF}} - 1)$$

Where V_{REF} = 1.23V, R1 between 1k Ω & 5k Ω

| PAD | FUNCTION | DESCRIPTION |
|-----------|------------------|--|
| 1 | V _{IN} | Supply input pin to collector pin of high-side transistor. Connect to power supply and input bypass capacitors C_{IN} . Path from V_{IN} pin to high frequency bypass C_{IN} and GND must be as short as possible. |
| 2 | V _{OUT} | Power transistor Emitter pin. This is a switching node. Attach this pin to an inductor & the cathode of the external diode. |
| 3 | FEEDBACK | Feedback sense input pin. Connect to the midpoint of feedback divider to set V _{OUT} . |
| 4 | ON / OFF | Voltage regulator enable input. High = OFF, Low = ON. Connect to GND to enable. Do not leave this pin floating. |
| 5 | GND | Ground pin. Path to C _{IN} must be as short as possible. |
| CHIP BACK | GND | Attach to heatsink or copper plane for thermal relief where required. |





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Absolute Maximum Ratings¹ (Voltages referenced to GND unless otherwise stated)

| PARAMETER | SYMBOL | VALUE | UNIT | |
|--|------------------|---------------------------|------|--|
| Supply Voltage | V _{CC} | 45 | V | |
| ON / OFF Pin input Voltage | V _{IN} | $-0.3V \le V \le +V_{IN}$ | V | |
| Output Voltage to Ground (Steady State) | V _{OUT} | -1 | V | |
| Power Dissipation | P _D | Internally Limited | W | |
| Storage Temperature | T _{STG} | -65 to +150 | °C | |
| Operating Junction Temperature | T _J | -40 to 125 | °C | |
| ESD Rating (C = $100pF$, R = $1.5k\Omega$) | V _{ESD} | ≥2 | kV | |

^{1.} Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings, for extended periods, may reduce device reliability.

Recommended Operating Conditions (Voltages referenced to GND unless otherwise stated)

| PARAMETER | SYMBOL | MIN | MAX | UNIT |
|-----------------------|-----------------|-----|------|------|
| Operating Temperature | T _J | -40 | +125 | °C |
| Supply Voltage | V _{cc} | - | 40 | V |

DC Electrical Characteristics² V_{IN} = 12V, I_{LOAD} = 500mA, T_J = -40°C to +125°C(unless noted otherwise)

| PARAMETER | SYMBOL CONDITIONS | | vie. | | LIMITS | | UNITS |
|-----------------------------------|---|--|-------------------------|-------|----------|-------|-------|
| PARAIVIETER | STWIDOL | CONDITIONS | | MIN | TYP | MAX | |
| | $V_{IN} = 12V, I_{LOAD} = 0.$ $V_{OUT} = 5V, T_{J} = 25$ | | | 1.217 | 1.230 | 1.243 | V |
| Feedback Voltage | V _{OUT} | | T _J = 25°C | 1.193 | 1.230 | 1.267 | \ |
| | | $0.5A \le I_{LOAD} \le 3.0A,$ $V_{OUT} = 5V$ | Full Range | 1.180 | <u>-</u> | 1.280 | V |
| Efficiency | η | V _{IN} =12V, I _{LOAD} = 3A,V _{OUT} = 5V | | - | 77 | _ | % |
| Feedback Bias | _ | \/ - F\/ | T _J = 25°C | - | 50 | 100 | |
| Current | l _b | V _{OUT} = 5V | Full Range | - | - | 500 | - nA |
| Oscillator Frequency ³ | £ . | T _J = 25°C | | 47 | 52 | 58 | kHz |
| Oscillator Frequency | f _o | | | 42 | - | 63 | KIIZ |
| Saturation Voltage ⁴ | ration Voltage ⁴ V _{SAT} I _{OUT} | 1 - 2 0 4 | T _J = 25°C | - | 1.4 | 1.8 | V |
| Saturation voitage | | I _{OUT} = 3.0A | Full Range | - | - | 2.0 | _ v |
| Max Duty Cycle (ON) ⁵ | DC | | | 93 | 98 | - | % |
| Current Limit ^{3, 4} | I _{CL} | | T _J = 25°C | 4.2 | 5.8 | 6.9 | A |
| | | | Full Range | 3.5 | - | 7.5 | |
| Output Leakage ⁶ | | Output = 0V, V _{IN} = 40V T _J = 25°C | | - | - | 2.0 | m A |
| Current | | | V T _J = 25°C | - | 7.5 | 30 | - mA |
| Quiescent Current ⁶ | IQ | T _J = 25°C | | - | 5 | 10 | mA |
| Standby Current | I _{STBY} | ON/OFF Pin = 5V(off), T _J = 25°C | | - | 50 | 200 | μA |

^{2.} External components such as the catch diode, inductor, input and output capacitors can affect switching regulator system performance. When the SiS2576-ADJ is used as shown in the Functional diagram with related external components, system performance will be as shown in system parameters section of Electrical Characteristics and associated figures.





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DC Electrical Characteristics V_{IN} = 12V, I_{LOAD} = 500mA, T_J = -40°C to +125°C(unless noted otherwise)

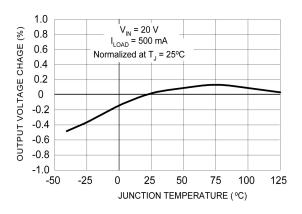
| PARAMETER | SYMBOL | CONDITIONS | | LIMITS | | | UNITS |
|-----------------------------------|-----------------|-----------------------|-----------------------|--------|-----|-----|-------|
| FANAIVILILIX | STWIDOL | | | MIN | TYP | MAX | UNITS |
| ON / OFF CONTROL | | | | | | | |
| ON / OFF Pin Logic Input Level | V _{IH} | V _{OUT} = 0V | T _J = 25°C | 2.2 | 1.4 | - | V |
| | | | Full Range | 2.4 | - | - | |
| | V _{IL} | | T _J = 25°C | - | 1.2 | 1.0 | |
| | | Full Range | - | - | 0.8 | | |
| ON / OFF Pin | I _{IH} | T - 25°C | | - | 12 | 30 | |
| Input Current | I _{IL} | T _J = 25°C | | - | 0 | 10 | μA |

^{3.} The oscillator frequency reduces to approximately 11 kHz in the event of an output short or an overload which causes the regulated output voltage to drop approximately 40% from the nominal output voltage. This self protection feature lowers the average dissipation of the IC by lowering the minimum duty cycle from 5% down to approximately 2%. 4. Output (Pad 2) sourcing current. No diode, inductor or capacitor connected to output.

5. Feedback (Pad 3) removed from output and connected to 0V. 6. Feedback (Pad 3) removed from output and connected to +12V, to force the output transistor "OFF"

1.4

Typical Performance Characteristics²



OUTPUT VOLTAGE CHAGE (%) 1.2 $I_{LOAD} = 500 \text{ mA}$ $T_J = 25^{\circ}\text{C}$ 1.0 8.0 0.6 5.0V 0.4 0.2 0 -0.2 -0.4 -0.6 10 50 0 30 40 60 INPUT VOLTAGE (V)

Figure 1 - Normalized output voltage

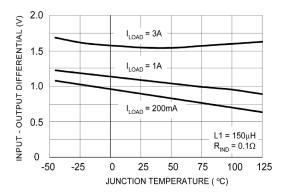


Figure 2 – Line Regulation

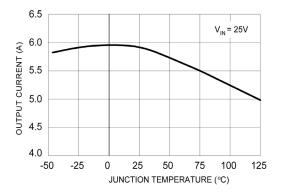


Figure 3 – Dropout Voltage

Figure 4 - Current Limit





Typical Performance Characteristics continued²

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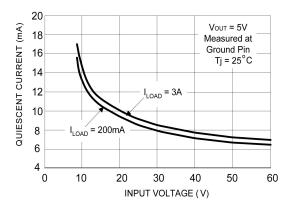


Figure 5 - Quiescent Current

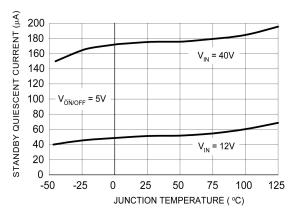


Figure 7 - Standby Quiescent Current

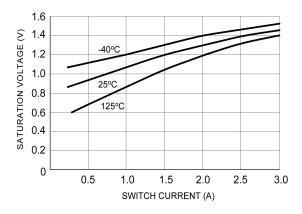


Figure 6 – Switch Saturation Voltage

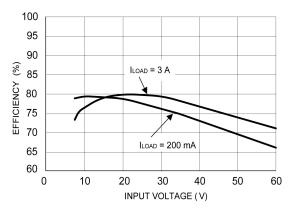


Figure 8 - Efficiency

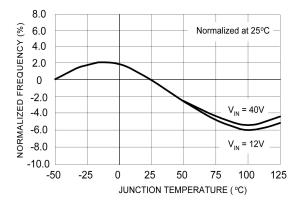


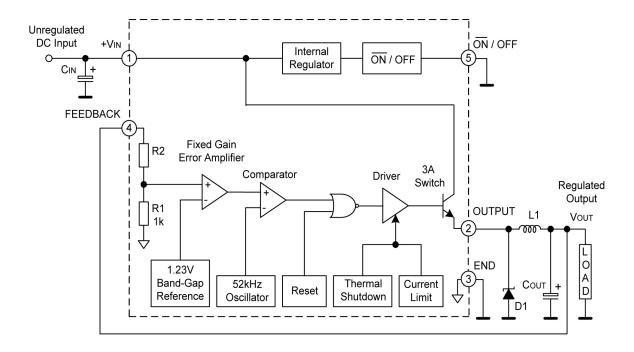
Figure 9 - Oscillator Frequency





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Block Diagram



R1 = Open, R2 = 0Ω

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